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April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

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## 2SK3162

# Silicon N Channel MOS FET High Speed Power Switching

REJ03G1087-0400

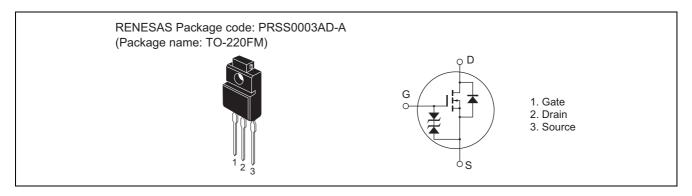
(Previous: ADE-208-735C)

Rev.4.00 Sep 07, 2005

#### **Features**

- Low on-resistance  $R_{DS} = 60 \ m\Omega \ typ.$
- High speed switching
- 4 V gate drive device can be driven from 5 V source

## **Outline**



## **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Ratings	Unit
Drain to source voltage	V <sub>DSS</sub>	200	V
Gate to source voltage	V <sub>GSS</sub>	±20	V
Drain current	I <sub>D</sub>	20	А
Drain peak current	I <sub>D(pulse)</sub> Note1	80	A
Body-drain diode reverse drain current	I <sub>DR</sub>	20	А
Avalanche current	I <sub>AP</sub> Note3	20	А
Avalanche energy	E <sub>AR</sub> Note3	26	mJ
Channel dissipation	Pch Note2	35	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW  $\leq$  10  $\mu$ s, duty cycle  $\leq$  1 %

2. Value at Tc = 25°C

3. Value at Tch = 25°C, Rg  $\geq$  50  $\Omega$ 

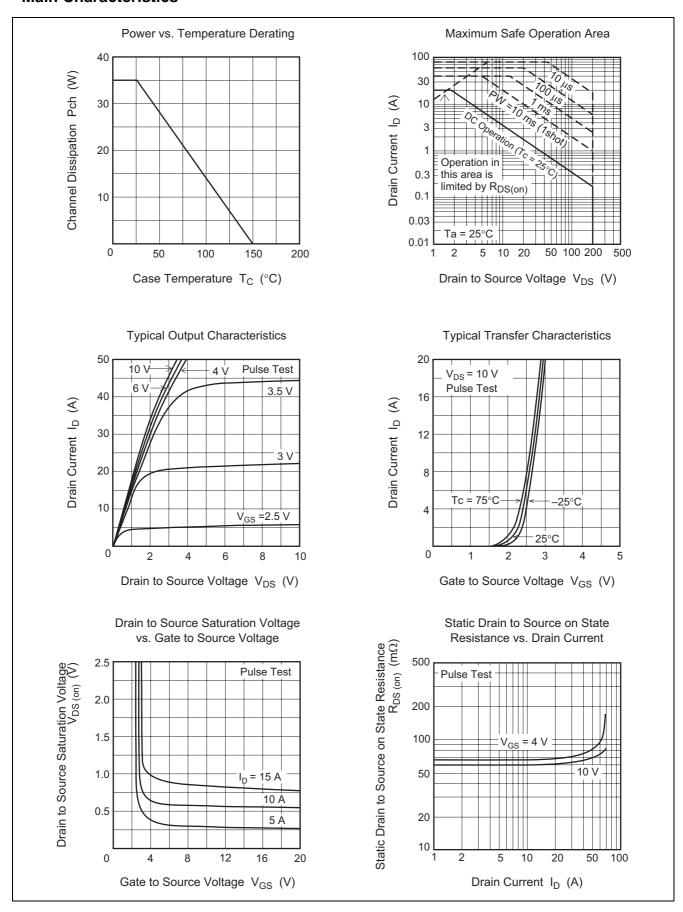
## **Electrical Characteristics**

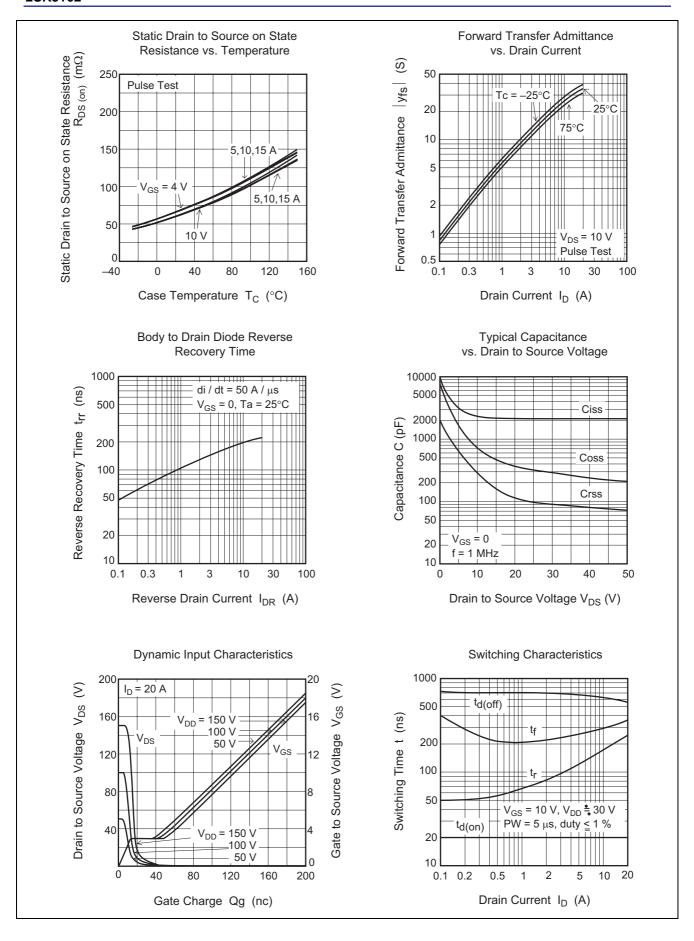
 $(Ta = 25^{\circ}C)$ 

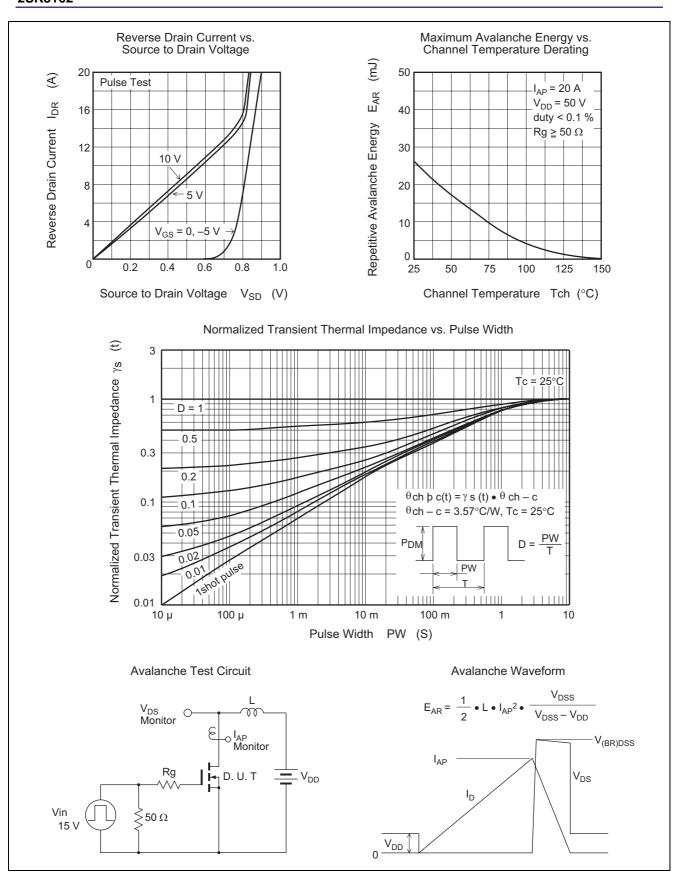
Item	Symbol	Min	Тур	Max	Unit	Test Conditions	
Drain to source breakdown voltage	V <sub>(BR)DSS</sub>	200	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$	
Gate to source breakdown voltage	V <sub>(BR)GSS</sub>	±20	_	_	V	$I_G = \pm 100 \ \mu A, \ V_{DS} = 0$	
Gate to source leak current	I <sub>GSS</sub>	_	_	±10	μΑ	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$	
Zero gate voltage drain current	I <sub>DSS</sub>	_	_	10	μΑ	$V_{DS} = 200 \text{ V}, V_{GS} = 0$	
Gate to source cutoff voltage	$V_{GS(off)}$	1.0	_	2.5	V	$I_D = 1 \text{ mA}, V_{DS} = 10 \text{ V}$	
Static drain to source on state	R <sub>DS(on)</sub>	_	60	75	mΩ	$I_D = 10 \text{ A}, V_{GS} = 10 \text{ V}^{Note4}$	
resistance	R <sub>DS(on)</sub>	_	65	85	mΩ	$I_D = 10 \text{ A}, V_{GS} = 4 \text{ V}^{\text{Note4}}$	
Forward transfer admittance	y <sub>fs</sub>	15	25	_	S	$I_D = 10 \text{ A}, V_{DS} = 10 \text{ V}^{\text{Note4}}$	
Input capacitance	Ciss	_	2420	_	pF	$V_{DS} = 10 \text{ V}, V_{GS} = 0,$	
Output capacitance	Coss	_	790	_	pF	f = 1 MHz	
Reverse transfer capacitance	Crss	_	340	_	pF		
Turn-on delay time	t <sub>d(on)</sub>	_	20	_	ns	$I_D = 10 \text{ A}, V_{GS} = 10 \text{ V},$	
Rise time	t <sub>r</sub>	_	150	_	ns	$R_L = 3 \Omega$	
Turn-off delay time	t <sub>d(off)</sub>	_	630	_	ns		
Fall time	t <sub>f</sub>	_	290	_	ns		
Body-drain diode forward voltage	$V_{DF}$	_	0.90	_	V	$I_F = 20A, V_{GS} = 0$	
Body-drain diode reverse recovery time	t <sub>rr</sub>	_	210	_	ns	$I_F = 20A$ , $V_{GS} = 0$ $di_F/dt = 50 A/ \mu s$	

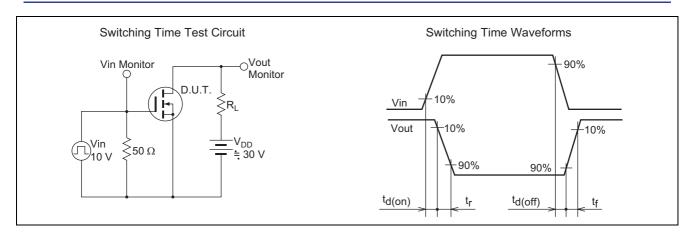
Note: 4. Pulse test

## **Main Characteristics**

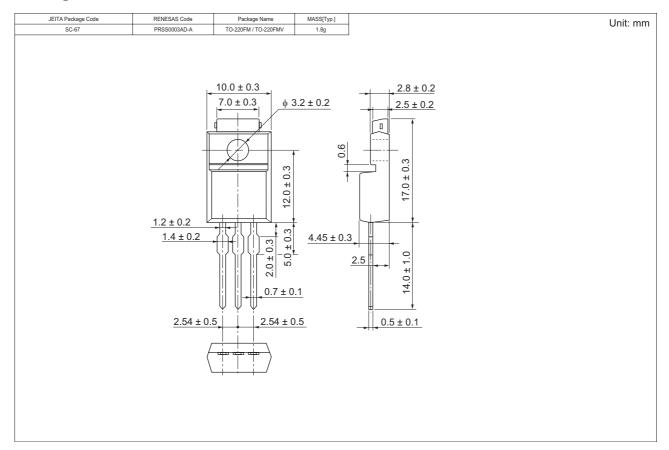








## **Package Dimensions**



## **Ordering Information**

Part Name	Quantity	Shipping Container
2SK3162-E	500 pcs	Box (Sack)

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